



**AAT11671**

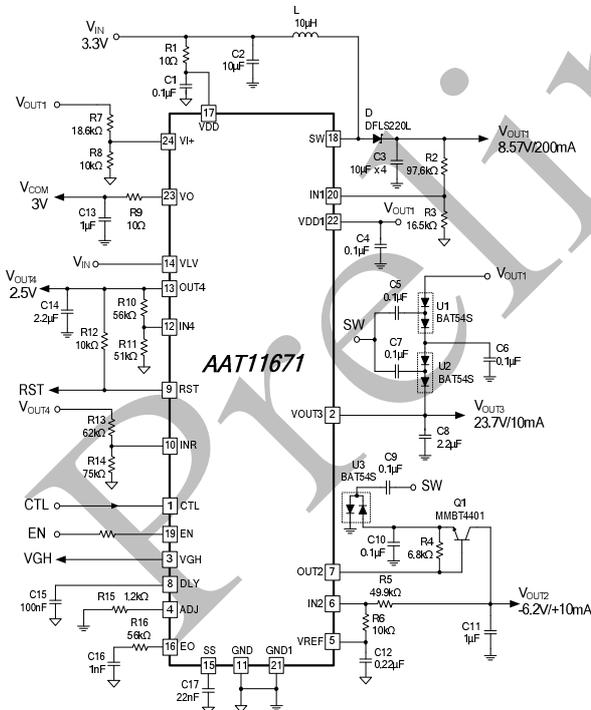
Product information presented is current as of publication date. Details are subject to change without notice.

**INTEGRATED TFT LCD POWER SOLUTION**

**FEATURES**

- Built In 2A (Max.), 0.2Ω Switching NMOS
- Negative LDO Driver Down to -14V/+20mA
- V<sub>COM</sub> Operational Amplifier
- Up to 350mA LDO
- Reset Signal Output for T<sub>COM</sub>
- 28V High Voltage Switch for VGH
- Adjustable Soft-Start Function
- 1.2MHz Fixed Switching Frequency
- Fault and Thermal Protection
- Low Dissipation Current :  
Typical 2.3mA In Operation
- VQFN24-4\*4 Package Available

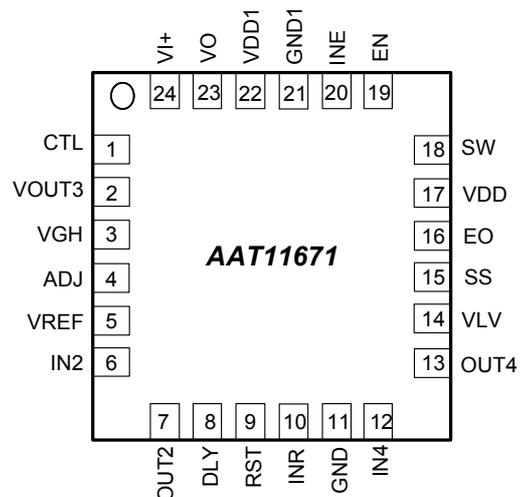
**TYPICAL APPLICATION**



**GENERAL DESCRIPTION**

The AAT11671 provides a step-up PWM controller, negative high voltage LDO drivers, low dropout linear regulator, V<sub>COM</sub> operational amplifier and one high voltage switch (up to 28V) for TFT LCD display. RST pin will issue a reset signal to T<sub>COM</sub> when V<sub>DD</sub> voltage is too low. The PWM controller consists of an on-chip voltage reference, oscillator, error amplifier, current sense circuit, comparator, under-voltage lockout protection and soft-start control circuit. The thermal and power fault protection prevents excessive power damaging internal circuit. The negative high voltage LDO drivers generate V<sub>OUT2</sub> voltage (VGL) setting by external resistor divider. For the flicker compensation, VGH will be connected to V<sub>OUT3</sub> when CTL is high and connected to ADJ when CTL goes low. The AAT11671 contains one operational amplifier capable of supplying 200mA to V<sub>COM</sub>. With the minimal external components, the AAT11671 offers a simple and economical solution for TFT LCD power.

**PIN CONFIGURATION**



**AAT11671****ORDERING INFORMATION**

DEVICE TYPE	PART NUMBER	PACKAGE	PACKING	TEMP. RANGE	MARKING	MARKING DESCRIPTION
AAT11671	AAT11671 - Q7-T	Q7: VQFN24- 4*4	T: Tape and Reel	-40 °C to +85 °C	AAT11671 XXXXX XXXX	1. Part Name 2. Lot No. (6~9 Digits) 3. Date Code (4 Digits)

Note: All AAT products are lead free and halogen free.

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
VDD, CTL, VLV to GND	$V_{DD}$	7	V
VDD1, SW to GND	$V_{H1}$	14	V
VOUT3 to GND	$V_{H2}$	28	V
OUT2 to GND	$V_{H3}$	-14	V
Input Voltage 1 (IN1, IN2, IN4, INR, DLY, EN, SS)	$V_{I1}$	$V_{DD} + 0.3$	V
Input Voltage 2 (VI+)	$V_{I2}$	$V_{H1} + 0.3$	V
Output Voltage 1 (EO, RST, OUT4, VREF)	$V_{O1}$	$V_{DD} + 0.3$	V
Output Voltage 2 (VO)	$V_{O2}$	$V_{H1} + 0.3$	V
Output Voltage 3 (ADJ, VGH)	$V_{O3}$	$V_{H2} + 0.3$	V
Operating Free-Air Temperature Range	$T_C$	-40 to +85	°C
Storage Temperature Range	$T_{STORAGE}$	-65 to +150	°C
Power Dissipation	$P_d$	1,300	mW



## ELECTRICAL CHARACTERISTICS

( $V_{IN} = 3.3V$ ,  $V_{DD1} = 10V$ , unless otherwise specified.)

### Operating Power

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
VDD Input Voltage Range	$V_{DD}$		2.3	-	5.5	V
VDD1 Input Voltage Range	$V_{DD1}$		6	-	14	V
VDD Under Voltage Lockout	$V_{UVLO}$	Rising	2.11	2.21	2.31	V
		Falling	2.01	2.11	2.21	
VDD Operating Current	$I_{VDD}$	$V_{IN1} = 1.5V$ , Not Switching	-	0.4	0.8	mA
		$V_{IN1} = 1.2V$ , Switching	-	2.3	5.0	mA
VDD1 Operating Current	$I_{VDD1}$	$V_{VI+} = 4V$	-	1.2	3.0	mA
VLV Operating Current	$I_{VLV}$	$V_{VLV} = 5V$ , $I_{OUT4} = 0mA$	-	0.2	0.4	mA
Thermal Shutdown	$T_{SHDN}$		-	160	-	$^{\circ}C$

### Reference Voltage

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Reference Voltage	$V_{REF}$	$I_{VREF} = 100\mu A$	1.224	1.240	1.256	V
Line Regulation		$I_{VREF} = 100\mu A$ , $V_{DD} = 2.6V \sim 5.5V$	-	2	5	%/V
Load Regulation		$I_{VREF} = 0 \sim 100\mu A$	-	1	5	%/mA

### Oscillator

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Oscillation Frequency	$f_{OSC}$		1.0	1.2	1.4	MHz
Maximum Duty Cycle	$D_{MAX}$		86	90	94	%



## ELECTRICAL CHARACTERISTICS

( $V_{IN} = 3.3V$ ,  $V_{DD1} = 10V$ , unless otherwise specified.)

### Soft Start & Fault Detect

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Channel 1 Soft Start Current	$I_{SS}$	$V_{SS} = 1V$	-2	-4	-6	$\mu A$
During Fault Protect Trigger Time	$t_{FP}$		150	164	180	ms
Channel 1 to Channel 2 Delay	$t_{D12}$		30	34	38	ms
Channel 2 to Channel 3 Delay	$t_{D23}$		23	27	31	ms
IN1 Fault Protection Voltage	$V_{F1}$		1.00	1.05	1.10	V
IN2 Fault Protection Voltage	$V_{F2}$		0.20	0.25	0.30	V

### EN Control Inputs Characteristics

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Input Low Voltage	$V_{IL}$		-	-	0.4	V
Input High Voltage	$V_{IH}$		1.4	-	-	V

### Error Amplifier (Channel 1)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Feedback Voltage	$V_{IN1}$		1.224	1.240	1.256	V
Input Bias Current	$I_{B1}$	$V_{IN1} = 1V$ to $1.5V$	-40	0	+40	nA
Feedback-Voltage Line Regulation		Level to Produce $V_{EO} = 1.24V$ $2.3V < V_{DD} < 5.5V$	-	0.05	0.15	%/V
Transconductance	$G_m$	$\Delta I = 5\mu A$	-	85	-	$\mu S$
Voltage Gain	$A_v$		-	1,500	-	V/V

**ELECTRICAL CHARACTERISTICS**(V<sub>IN</sub> = 3.3V, V<sub>DD1</sub> = 10V, unless otherwise specified.)**N-MOS Switch**

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Current Limit	I <sub>LIM</sub>		-	2	-	A
On-Resistance	R <sub>ON</sub>	I <sub>SW</sub> = 1.0A	-	0.2	-	Ω
Leakage Current	I <sub>SWOFF</sub>	V <sub>SW</sub> = 12V	-	0.01	20.00	μA

**Negative LDO Driver (Channel 2)**

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
IN2 Threshold Voltage	V <sub>IN2</sub>	I <sub>OUT2</sub> = -100μA	-15	0	+15	mV
IN2 Input Bias Current	I <sub>B2</sub>	V <sub>IN2</sub> = -0.25V to +0.25V	-40	0	+40	nA
OUT2 Source Current	I <sub>OUT2</sub>	V <sub>IN2</sub> = 0.5V, OUT2 = -10V	4	20	40	mA

**Low Voltage LDO**

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Input Voltage Range	V <sub>VLV</sub>		2.5	-	5.5	V
IN4 Threshold Voltage	V <sub>IN4</sub>	I <sub>OUT4</sub> = 100mA	1.224	1.240	1.256	V
IN4 Input Bias Current	I <sub>B4</sub>	V <sub>IN4</sub> = 0V to 1.5V	-40	0	+40	nA
Dropout Voltage	V <sub>DROP</sub>	I <sub>OUT4</sub> = 250mA	-	350	500	mV
LDO Output Current	I <sub>OUT4</sub>		350	-	-	mA
LDO Output Current Limit	I <sub>LIM4</sub>		-	500	-	mA
Line Regulation		Measure V <sub>IN4</sub> , V <sub>VLV</sub> = 2.5 ~ 5V	-	-	5	%/V
Load Regulation		Measure V <sub>IN4</sub> , I <sub>OUT4</sub> = 20mA ~ 300mA	-	-	0.1	%/mA

**AAT11671****ELECTRICAL CHARACTERISTICS**(V<sub>IN</sub> = 3.3V, V<sub>DD1</sub> = 10V, unless otherwise specified.)**High Voltage Switch Controller**

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
CTL Input Low Voltage	V <sub>IL</sub>		-	-	0.5	V
CTL Input High Voltage	V <sub>IH</sub>		2	-	-	V
CTL Input Bias Current	I <sub>B4</sub>	CTL = 0 to V <sub>DD</sub>	-40	0	+40	nA
Propagation Delay CTL to VGH (Form Low to High)	T <sub>PPLH</sub>	V <sub>OUT3</sub> = 25V	-	170	-	ns
Propagation Delay CTL to VGH (Form High to Low)	T <sub>PPHL</sub>	V <sub>OUT3</sub> = 25V	-	110	-	ns
VOUT3 to VGH Switch R-On	R <sub>ONSC</sub>	DLY = 1.5V, CTL = VDD	-	30	60	Ω
ADJ to VGH Switch R-On	R <sub>ONDC</sub>	DLY = 1.5V, CTL = GND	-	50	100	Ω

**Reset Output**

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Operating Voltage	V <sub>OP</sub>		1.6	-	-	V
RST Output Voltage	V <sub>RST</sub>	I <sub>RST</sub> = 1.2mA	-	-	0.2	V
INR Threshold Voltage	V <sub>INR</sub>		-	1.1	-	V
DLY Source Current	I <sub>DLY</sub>	V <sub>DLY</sub> = 1V	-5	-10	-15	μA
DLY Threshold Voltage	V <sub>DLY</sub>		1.20	1.24	1.28	V

**V<sub>COM</sub> Buffer**

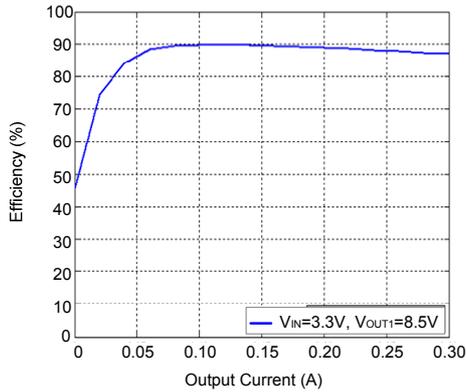
PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Input Offset Voltage	V <sub>OS</sub>	V <sub>VI+</sub> = 4V	-	2	12	mV
Input Bias Current	I <sub>B5</sub>	V <sub>VI+</sub> = 4V	-40	0	+40	nA
Output Swing	V <sub>OH</sub>	I <sub>VO</sub> = -50mA, V <sub>VI+</sub> = 4V	-	4.53	4.76	V
	V <sub>OL</sub>	I <sub>VO</sub> = 50mA, V <sub>VI+</sub> = 4V	3.24	3.47	-	
Short Circuit Current	I <sub>SHORT</sub>	Measure I <sub>VO</sub>	-	±200	-	mA
Slew Rate	SR	V <sub>VI+</sub> = 2V to 8V, V <sub>VI+</sub> = 8V to 2V, 20% to 80%	-	12	-	μs
Settling Time	t <sub>S</sub>	V <sub>VI+</sub> = 3.5V to 4.5V, 90%	-	5	-	μs



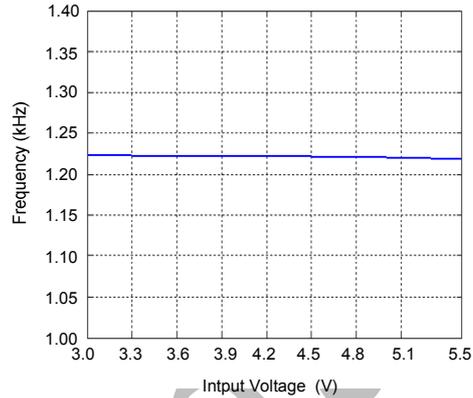
# TYPICAL OPERATING CHARACTERISTICS

( $V_{IN} = 3.3V$ ,  $V_{OUT1} = 8.5V$ ,  $V_{OUT2} = -6V$ ,  $V_{OUT3} = 22V$ ,  $T_C = +25^\circ C$ , unless otherwise noted.)

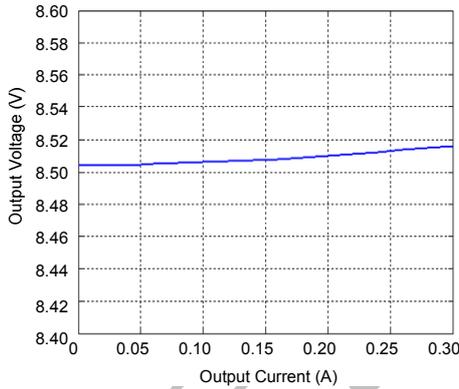
Boost Converter Efficiency vs. Output Current



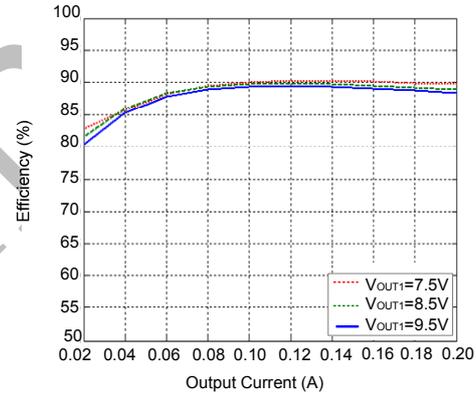
Boost Converter Frequency vs. Input Voltage



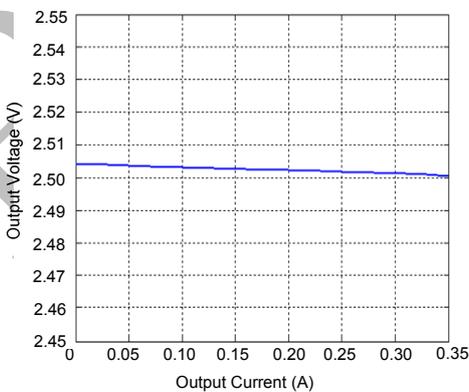
Boost Converter Output Voltage vs. Output Current



Boost Converter Efficiency vs. Output Current



Boost Converter Output Voltage vs. Output Current (VOUT4)



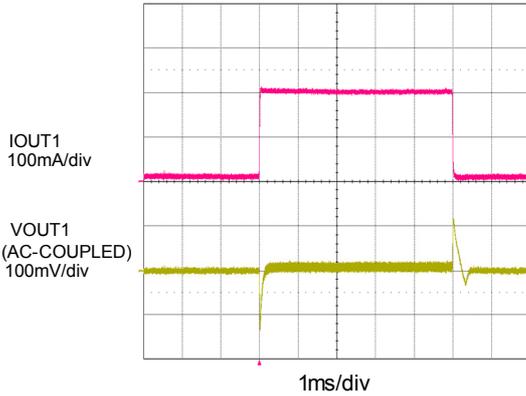


# TYPICAL OPERATING CHARACTERISTICS

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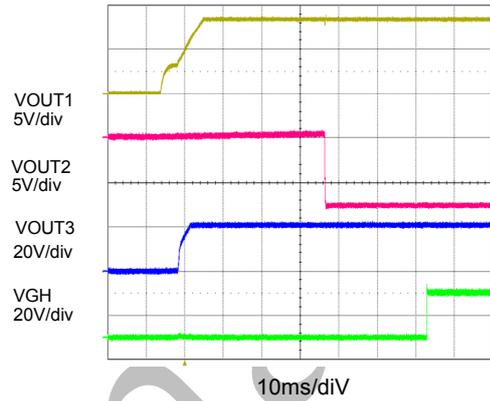
### Boost Converter Transient Response

$I_{OUT1} = 10mA$  to  $200mA$



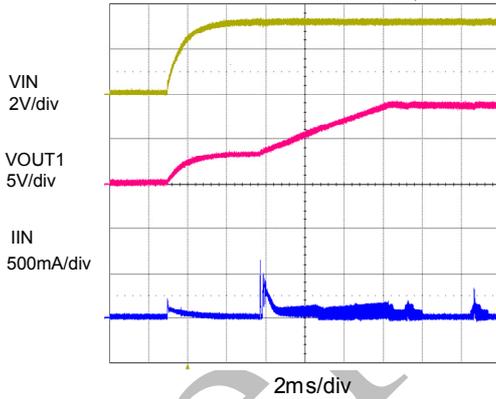
### Power On Sequence

$CDLY = 0.1\mu F$ ,  $CSS = 33nF$   
 $I_{OUT1} = 200mA$ ,  $I_{OUT2} = 10mA$ ,  $I_{OUT3} = 5mA$



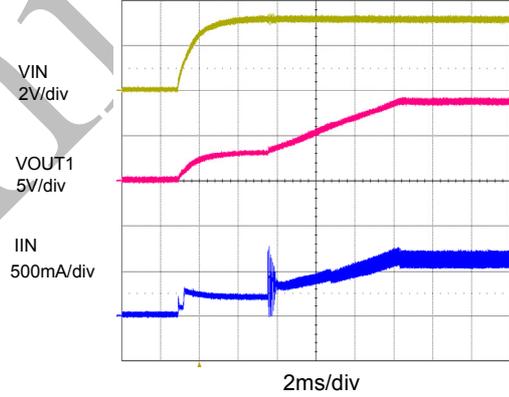
### Boost Converter Soft-Start

$I_{OUT1} = 0mA$ ,  $CSS = 33nF$



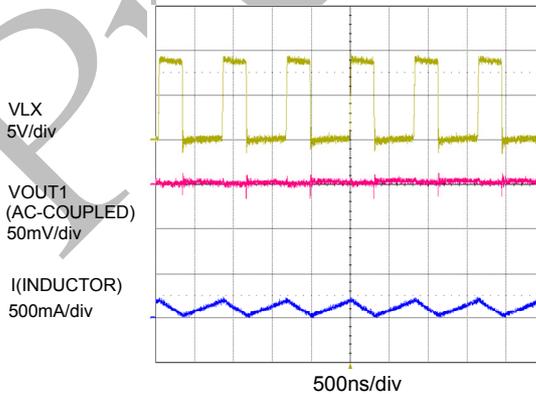
### Boost Converter Soft-Start

$I_{OUT1} = 200mA$ ,  $CSS = 33nF$



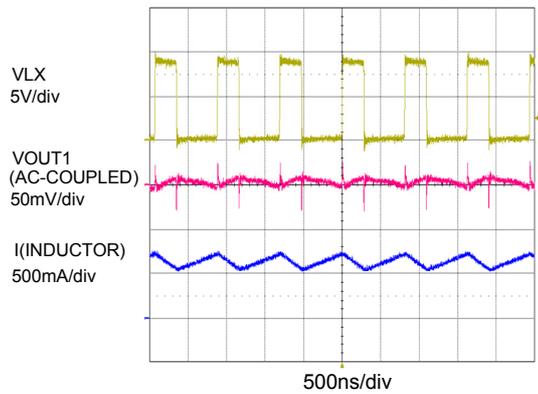
### Boost Converter Stability

$I_{OUT1} = 20mA$



### Boost Converter Stability

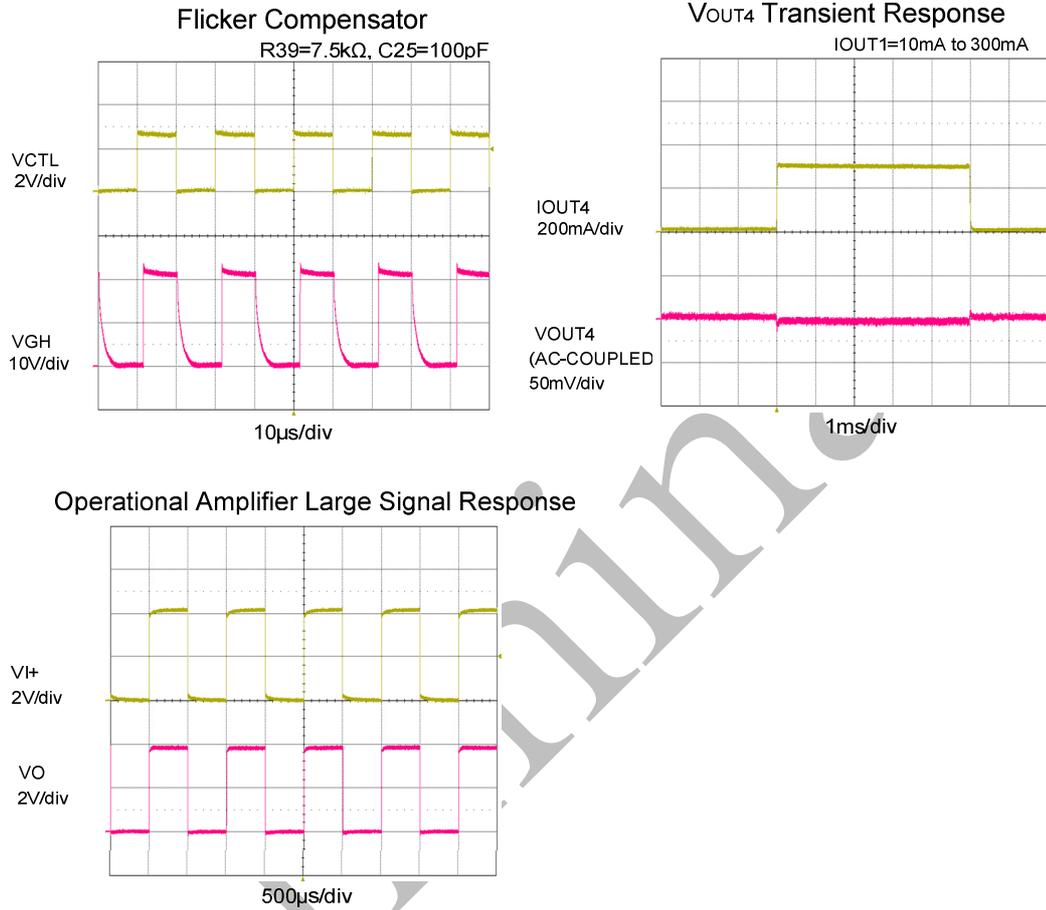
$I_{OUT1} = 200mA$





## TYPICAL OPERATING CHARACTERISTICS

( $V_{IN} = 3.3V$ ,  $V_{OUT1} = 8.5V$ ,  $V_{OUT2} = -6V$ ,  $V_{OUT3} = 22V$ ,  $T_C = +25^\circ C$ , unless otherwise noted.)



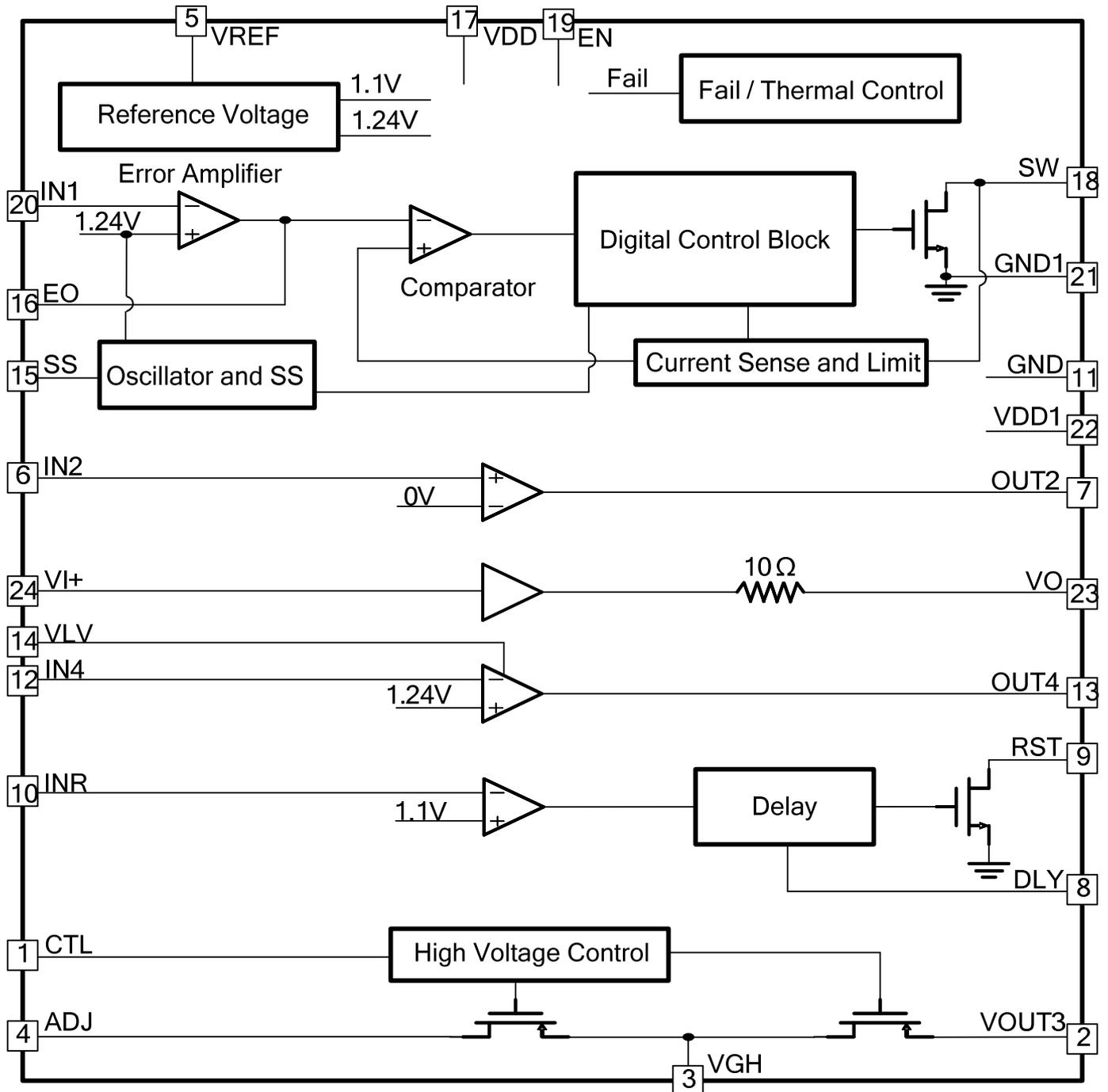
**PIN DESCRIPTION**

PIN NO.	NAME	I/O	DESCRIPTION
QFN-24			
1	CTL	I	High Voltage Switch Control Pin
2	VOU3	-	Gate High Voltage Input (Channel 3 Output Voltage)
3	VGH	O	Switching Gate High Voltage for TFT
4	ADJ	O	Gate High Voltage Fall Time Setting Pin
5	VREF	O	Internal Reference Voltage Output
6	IN2	I	Negative Voltage LDO Feedback Pin
7	OUT2	O	Negative Voltage LDO Output
8	DLY	I	Reset Signal Delay Control
9	RST	O	Reset Signal Output
10	INR	I	Reset Signal Detection Input
11	GND	-	Ground
12	IN4	I	Low Voltage LDO Feedback Pin
13	OUT4	O	Low Voltage LDO Output Pin
14	VLV	-	Low Voltage Power Pin
15	SS	I	Main PWM Soft Start Control Pin
16	EO	O	Main PWM Error Amplifier Output
17	VDD	-	Power Supply Input
18	SW	-	Main PWM Switching Pin
19	EN	I	Main PWM Enable and OCP Control Pin
20	IN1	I	Main PWM Feedback Pin
21	GND1	-	SW MOS Ground
22	VDD1	-	High Voltage Power Supply Input
23	VO	O	Operational Amplifier Output
24	VI+	I	Operational Amplifier Positive Input



# FUNCTION BLOCK DIAGRAM

AAT11671



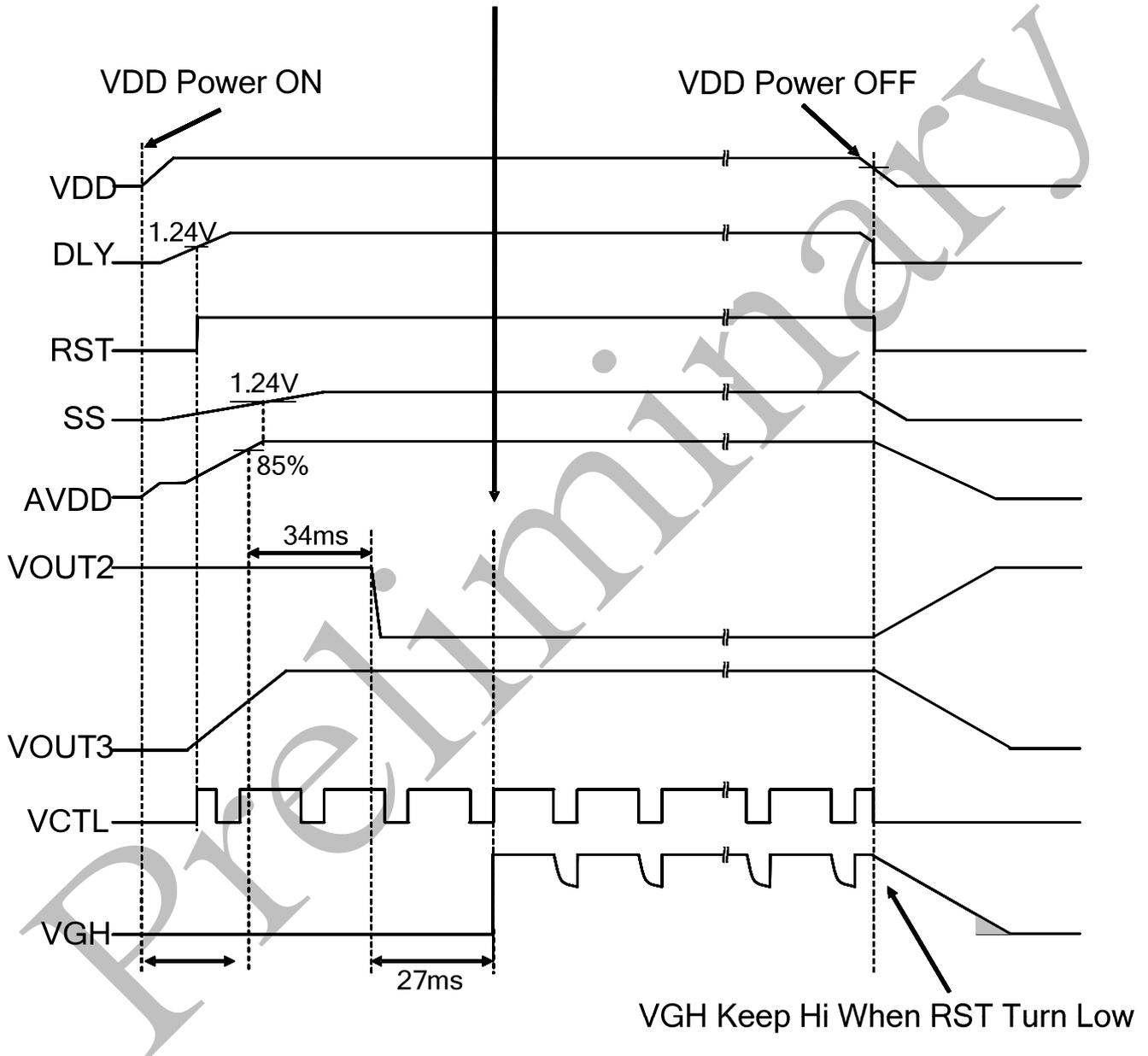




# POWER ON AND POWER OFF TIMING CHART

AAT11671

Enable Fault Detection ( 164ms Debounce)





## DESIGN PROCEDURE

### Boost Converter Design Inductor Selection

The minimum inductor value is selected to make sure that the system operates in continuous conduction mode (CCM) for high efficiency and to prevent EMI. The equation of inductor used a parameter  $\kappa$ , which is the ratio of the inductor peak to peak ripple current to the input DC current. The best trade-off between voltage ripple of transient output current and permanent output current has a  $\kappa$  between 0.2 and 0.4.

$$L \geq \frac{\eta V_O}{\kappa I_{OFS}} D(1-D)^2, \quad D = 1 - \frac{V_{IN}}{V_O}, \quad \kappa = \frac{\Delta I_{L(\text{peak-peak})}}{I_{IN}}$$

$\eta$ : Boost converter efficiency

$\kappa$ : The ratio of the inductor peak to peak ripple current to the input DC current

$V_{IN}$ : Input voltage

$V_O$ : Output voltage

$I_O$ : Output load current

$f_S$ : Switching frequency

$D$ : Duty cycle

$\Delta I_{L(\text{peak-peak})}$ : Inductor peak to peak ripple current

$I_{IN}$ : Input DC current

The AAT11671 SW current limit ( $I_{LIM}$ ) and inductor's saturation current rating ( $I_{LSAT}$ ) should exceed  $I_{L(\text{peak})}$ , and the inductor's DC current rating should exceed  $I_{IN}$ . For the best efficiency, choose an inductor with less DC resistance ( $r_L$ ).

$$I_{LIM} \text{ and } I_{LSAT} > I_{L(\text{peak})}$$

$$I_{LDC} > I_{IN}$$

$$I_{L(\text{peak})} = I_{IN} + \frac{V_{IN} D}{2L f_S}$$

$$I_{IN} = \frac{I_O}{\eta(1-D)}, \quad P_{DCR} \approx \left( \frac{I_O}{\eta(1-D)} \right)^2 r_L$$

$I_{LDC}$ : DC current rating of inductor

$P_{DCR}$ : Power loss of inductor series resistance

Table 1. Inductor Data List

C6-K1.8L	$r_L$	DC CURRENT RATING
3.9 $\mu$ H	41m $\Omega$	2.5A
6.8 $\mu$ H	68m $\Omega$	2.2A
10 $\mu$ H	81m $\Omega$	1.8A
MITSUMI Product-Max Height: 1.9mm		

Example: In the typical application circuit (Figure 1) the output load current is 200mA with 8.6V output voltage and input voltage of 3.3V. Choose a  $\kappa$  of 0.3 and efficiency of 90%.

$$L \geq \frac{0.9 * 8.6}{0.3 * 0.2 * 1.2^6} 0.6163(0.3837)^2 \approx 10\mu\text{H}$$

$$I_{IN} = \frac{I_O}{\eta(1-D)} = 0.579\text{A}$$

$$I_{L(\text{peak})} = I_{IN} + \frac{V_{IN} D}{2L f_S} = 0.664\text{A}$$

$$P_{DCR} = 0.0272\text{W} \text{ or } 1.58\% \text{ power loss}$$

### Rectifier Diode Selection

The Schottky diode is recommended to apply in switching converter. To achieve the best efficiency, choose a Schottky diode with less recovery capacitor ( $C_T$ ) for fast recovery time and low forward voltage ( $V_F$ ). For boost converter, the reverse voltage rating ( $V_R$ ) should be higher than the maximum output voltage, and the current rating should exceed the maximum inductor current.

$$P_{DIODE} = P_{DSW} + P_{DCOM}$$

$$P_{DSW} = (1-D) V_F Q_R f_S$$

$$Q_R = V_R C_T$$

$$P_{DCOM} = V_{FLO} (1-D)$$

$P_{DIODE}$ : Total power loss of diode for boost converter

$P_{DSW}$ : Switching loss of diode for boost converter

$P_{DCOM}$ : Conduction loss of diode for boost converter



**AAT11671**

**Table 2. Schottky Data List**

SMA	V <sub>F</sub>	V <sub>R</sub>	C <sub>T</sub>
B220A	0.24V	14V	150pF
B240A	0.24V	28V	150pF
DIODES Product-MAX Height: 2.3mm			

**Input Capacitor Selection**

The input capacitors have two important functions in PWM controller. First, an input capacitor provides the power for soft start procedure and supply the current for the gate-driving circuit. A 10µA ceramic capacitor is sufficient for most of the applications. Second, an input bypass capacitor reduces the current peaks, the input voltage drop, and noise injection into the IC. A low ESR ceramics capacitor 0.1µF is used in typical circuit. The bypass capacitor is required as close as possible from VDD (Pin17) and GND (Pin11). To ensure the low noise supply at VDD, VDD is decoupled from input capacitor using an RC low pass filter.

**Output Capacitor Selection**

The output capacitor maintains the DC output voltage. A Low ESR (r<sub>C</sub>) ceramic capacitor is recommended for the smaller output ripple and power loss. There are two parameters which can affect the output voltage ripple: 1. the voltage drops when the inductor current flows through the ESR of output capacitor; 2. charging and discharging of the output capacitor also affect the output voltage ripple.

$$V_{\text{RIPPLE}} = V_{\text{RIPPLE}}(C_{\text{OUT}}) + V_{\text{RIPPLE}}(\text{ESR})$$

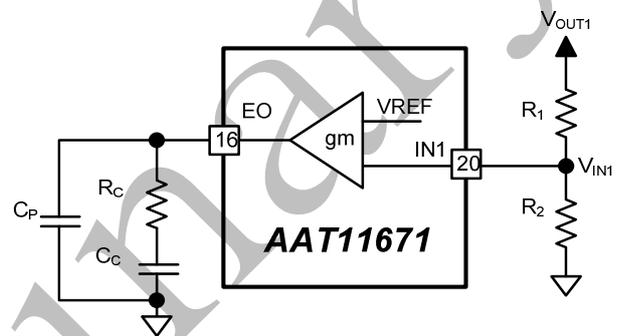
$$V_{\text{RIPPLE}}(C_{\text{OUT}}) \approx \frac{I_o D}{f_s C_{\text{OUT}}}$$

$$V_{\text{RIPPLE}}(\text{ESR}) \approx I_{L(\text{peak})} r_C$$

**Setting the Output Voltage**

The output voltage of boost converter is set by the resistor divider from the output (V<sub>OUT1</sub>) to GND with the center tap connected to the IN1. Where V<sub>IN1</sub>, the boost converter feedback regulation voltage is 1.24V. Choose R<sub>2</sub> (Figure 1) between 5.1kΩ and 51kΩ and calculate R<sub>1</sub> to satisfy the following equation.

$$R_1 = R_2 \left( \frac{V_{\text{OUT1}}}{V_{\text{IN1}}} - 1 \right)$$



**Figure 1. Feedback Circuit**

**Loop Compensation Design**

The loop compensation is consisted by the external resistor R<sub>C</sub>, capacitor C<sub>C</sub> and capacitor C<sub>P</sub>. Choose R<sub>C</sub> to set the high frequency integrator gain for fast transient response. Choose C<sub>C</sub> to set the integrator zero to maintain loop stability. To improve the transient response, either the R<sub>C</sub> value can be increased or the C<sub>C</sub> value can be reduced. However, resistor value that is too high or capacitor value that is too low will reduce loop stability. The better compensation value for V<sub>IN</sub> = 3.3V is recommended by R<sub>C</sub> = 56k, C<sub>C</sub> = 1nF, C<sub>P</sub> = NC.

**Soft-Start Selection**

The AAT11671 has an adjustable soft-start to prevent high inrush current during start up. The soft-start function is implemented by the external capacitor with a 4µA constant current. The typical soft-start capacitance range is from 22nF to 220nF. A 100nF capacitor is usually sufficient for most of the applications.



**AAT11671**

**Negative LDO Driver  
Output Voltage Selection**

The output voltage of negative LDO driver is set by a resistive divider from the output ( $V_{OUT2}$ ) to  $V_{REF}$  with the center tap connected to the  $IN2$ , where  $IN2$ , the negative LDO driver feedback regulation voltage is 0V. Choose  $R6$  (Figure 2) between 5.1kΩ and 51kΩ and calculate  $R5$  with the following equation:

$$R5 = R6 \left( \frac{-V_{OUT2}}{V_{REF}} \right)$$

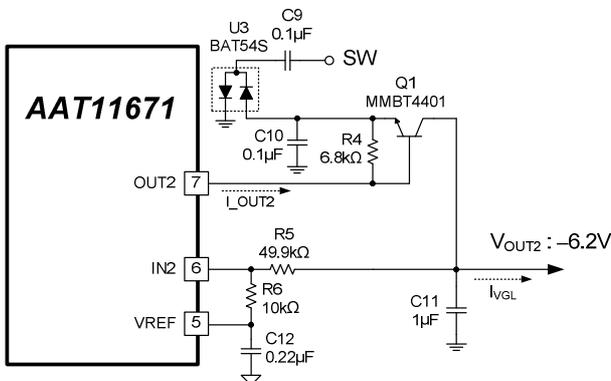


Figure 2. The Negative LDO Driver

**Calculation of Negative LDO Driver  
Base-Emitter Resistor**

For the AAT11671, the minimum drive current for negative LDO driver is 4mA, thus the minimum base-emitter resistance can be calculated by the following equation:

$$R4_{(min)} \geq V_{BE(max)} / (I_{OUT2(min)} - (I_{VGL} / h_{fe(min)}))$$

Choose resistor  $R4$  to be 6.8kΩ is usually sufficient for most of the applications.

Table 3. Pass Transistor Specifications

	MMBT4401 (NPN)
$V_{BE(max)}$	0.65V
$h_{fe(min)}$	130
DIODES Product, Case: SOT23	

**Flying Capacitors**

Increasing the flying capacitor (Figure 2,  $C9$ ) values can lower output voltage ripples. A 0.1μF ceramic capacitor works well in negative LDO driver.

**LDO Driver Diode**

To achieve high efficiency, a Schottky diode should be used. BAT54S (Figure 2,  $U3$ ) has fast recovery time and low forward voltage for the best efficiency.

**Setting the LDO Voltage**

The LDO voltage is set by the resistor divider from the  $V_{OUT4}$  to GND with the center tap connected to the  $IN4$ . Where  $IN4$ , the LDO feedback regulation voltage is 1.24V. Choose  $R2$  (Figure 3) between 5.1kΩ and 51kΩ and calculate  $R1$  to satisfy the following equation.

$$R13 = R14 \left( \frac{V_{OUT4}}{IN4} - 1 \right)$$

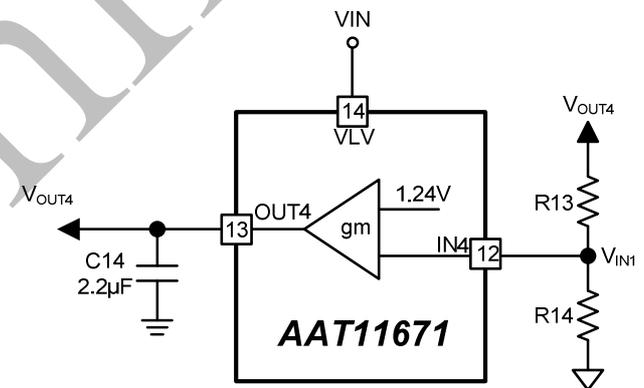


Figure 3. LDO Circuit

**Reset Voltage design**

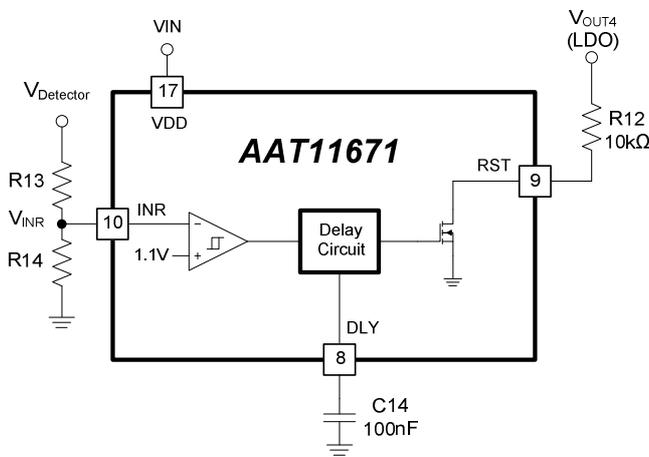
The AAT11671 has an integrated reset voltage detector with an open drain output. When  $V_{INR}$  value is under the  $INR$  threshold voltage 1.1V, the pin RST would be pulled low by inside MOS. The  $V_{Detector}$  can be calculated as below :

$$V_{Detector} = 1.1V \times \left( 1 + \frac{R13}{R14} \right)$$

$$R13 = \left( \frac{V_{Detector}}{1.1V} - 1 \right) \times R14$$

$R14$  is recommended to be between 5.1kΩ and 30kΩ.

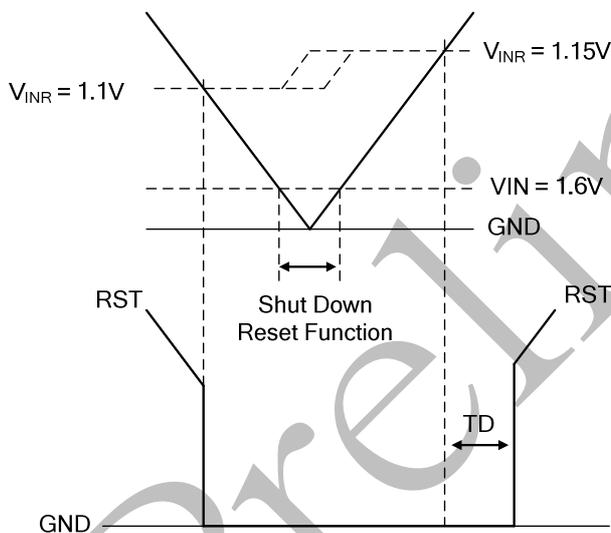
**AAT11671**



**Figure 4. The Application Circuit of Reset Function**

The delay time (TD) is set by capacitor C14. The delay time (TD) can be calculated as below:

$$T_D = \frac{C14 * 1.24V}{10\mu A}$$



**Figure 5. The Timing Chart of Reset Function**

**V<sub>COM</sub> Buffer**

The V<sub>COM</sub> buffer is usually used to drive V<sub>COM</sub> for TFT-LCD. The buffer is not designed to drive high capacitive loads, so it is recommended to connect a low pass filter with 10Ω resistor and 1μF capacitor. This would provide stable operation when driving high capacitive load.

**LAYOUT CONSIDERATION**

The system's performances including switching noise, transient response, and PWM feedback loop stability are greatly affected by the PC board layout and grounding. There are some general guidelines for layout:

**Inductor**

Always try to use a low EMI inductor with a ferrite core.

**Filter Capacitors**

Place low ESR ceramics filter capacitors (between 0.1μF and 0.22μF) close to VDD and VREF pins. This will eliminate as much trace inductance effects as possible and give the internal IC rail a cleaner voltage supply. The ground connection of the VDD and VREF by pass capacitor should be connected to the analog ground pin (GND) with a wide trace.

**Output Capacitors**

Minimize the length and maximize the width of traces to get the best transient response and reduce the ripple noise. We choose 10μF ceramics capacitor to reduce the ripple voltage, and use 0.1μF ceramics capacitor to reduce the ripple noise.

**Feedback**

If external compensation components are needed for stability, they should also be placed close to the IC. Take care to avoid the feedback voltage-divider resistors' trace near the SW. Minimize feedback track lengths to avoid the digital signal noise of TFT control board.

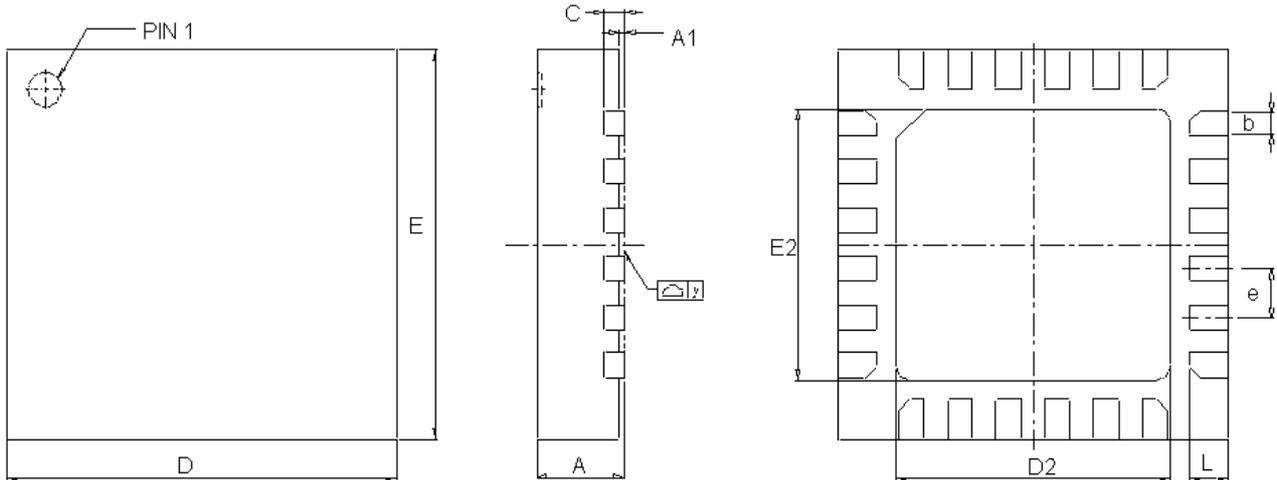
**Ground Plane**

The grounds of the IC, input capacitors, and output capacitors should be connected close to a ground plane. It would be a good design rule to have a ground plane on the PCB. This will reduce noise and ground loop errors as well as absorb more of the EMI radiated by the inductor. For boards with more than two layers, a ground plane can be used to separate the power plane and the signal plane for improved performance.



## PACKAGE DIMENSION

### VQFN-24 4\*4



Symbol	Dimensions In Millimeters		
	MIN	TYP	MAX
A	0.75	0.90	1.00
A1	0	0.02	0.05
b	0.18	0.23	0.30
C	0.19	0.20	0.25
D	3.90	4.00	4.10
D2	2.70	2.80	2.90
E	3.90	4.00	4.10
E2	2.70	2.80	2.90
e	----	0.50	----
L	0.30	0.40	0.50
y	0	----	0.076